

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}\text{C}$ Unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F)		1.2	1.5	V	$I_F = 10\text{mA}$
	Reverse Current (I_R)			10	μA	$V_R = 6\text{V}$
Output	Collector-emitter Breakdown (BV_{CEO}) (note 2)	70			V	$I_C = 1\text{mA}$
	Collector-base Breakdown (BV_{CBO})	70			V	$I_C = 100\mu\text{A}$
	Emitter-collector Breakdown (BV_{ECO})	6			V	$I_E = 100\mu\text{A}$
	Collector-emitter Dark Current (I_{CEO})			50	nA	$V_{CE} = 10\text{V}$
Coupled	Current Transfer Ratio (CTR) H11AV1	100		300	%	$10\text{mA } I_F, 10\text{V } V_{CE}$
	H11AV2	50			%	$10\text{mA } I_F, 10\text{V } V_{CE}$
	H11AV3	20			%	$10\text{mA } I_F, 10\text{V } V_{CE}$
	Collector-emitter Saturation Voltage $V_{CE(SAT)}$			0.4	V	$20\text{mA } I_F, 2\text{mA } I_C$
	Input to Output Isolation Voltage V_{ISO}	5300 7500			V_{RMS} V_{PK}	See note 1 See note 1
	Input-output Isolation Resistance R_{ISO}	5×10^{10}			Ω	$V_{IO} = 500\text{V}$ (note 1)
	Rise Time, tr Fall Time, tf		2 2		μs μs	$V_{CC} = 5\text{V}$, fig 1 $I_F = 10\text{mA}, R_L = 75\Omega$

Note 1 Measured with input leads shorted together and output leads shorted together.
Note 2 Special Selections are available on request. Please consult the factory.

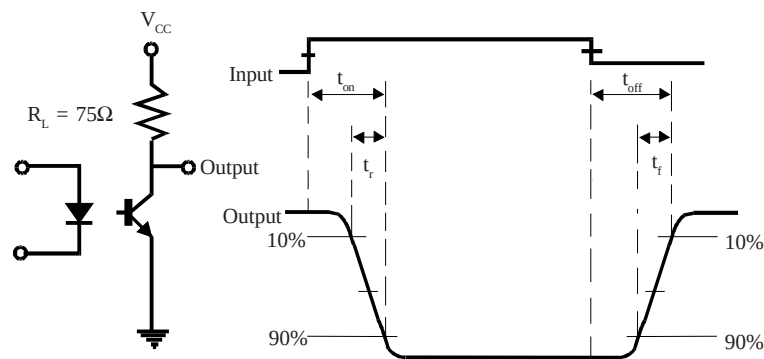
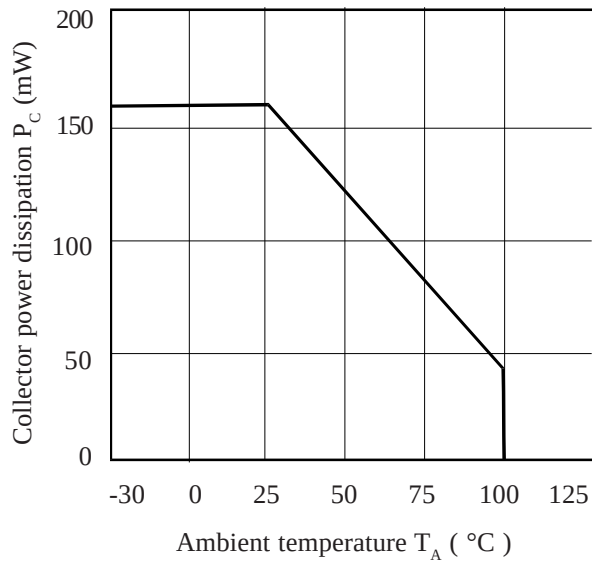
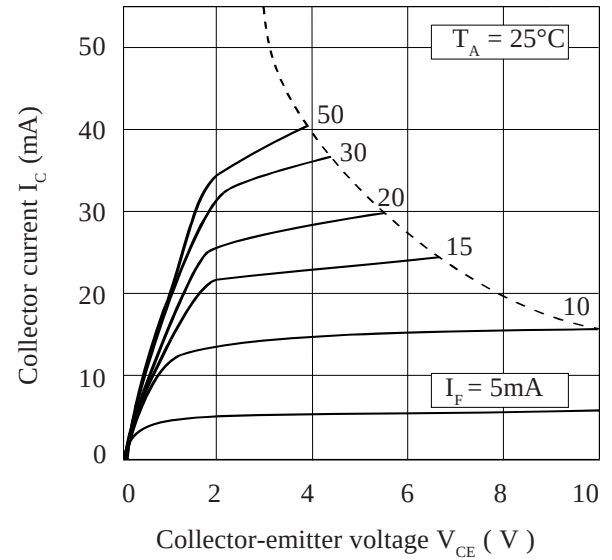


FIG 1

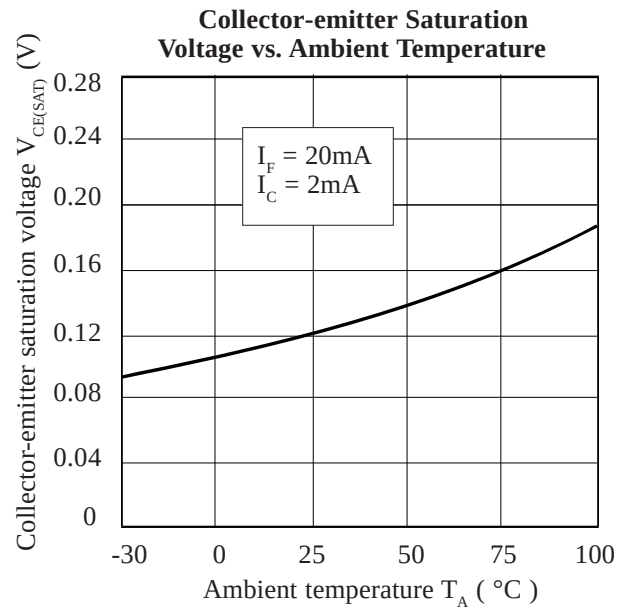
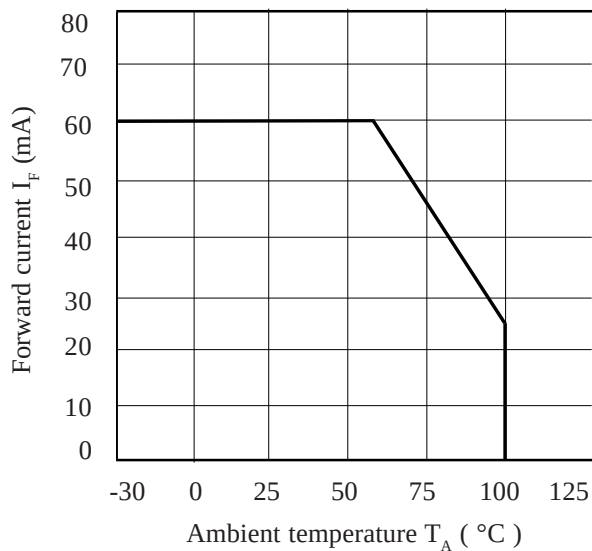
Collector Power Dissipation vs. Ambient Temperature



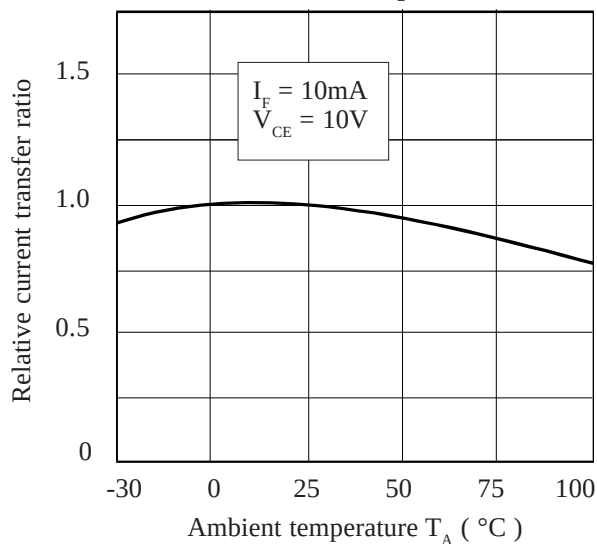
Collector Current vs. Collector-emitter Voltage



Forward Current vs. Ambient Temperature



Relative Current Transfer Ratio vs. Ambient Temperature



Relative Current Transfer Ratio vs. Forward Current

